

Quarterly Reliability Monitoring Results

Quarters: Q1/2022 to Q4/2023

Based on structural similarity

| Supplier | | User Part Number | | | | | | |
|--|--|---|-----------------------|-----------|------------|-----------|--|--|
| Nexperia B.V. Name of Laboratory Nexperia ATGD Based on AEC-Q101 Test | | PUSB3CB4 | | | | | | |
| | | Part Description | | | | | | |
| | | NXP ICN8 Protection INDI | | | | | | |
| | | MCD package, Subcon UTAC | | | | | | |
| | | Test Conditions | Duration | # Lots | # Quantity | # Rejects | | |
| | TEST | | | | | | | |
| | Pre- and Post-Stress | | | | | | | |
| # 1 | Electrical Test | Tamb = 25 °C | N/A | see below | all parts | see below | | |
| | PC | JESD22-A113 Bake Tamb = 125 °C Soak Tamb = 85 °C, RH = 85% | 24 hours 168 hours | | | | | |
| # 2 | Preconditioning | Reflow soldering | 3 cycles | 69 | 3000 | 0 | | |
| # 5 | HTRB High Temperature Reverse Bias | MIL-STD-750-1 M1038 Method A Tj = Tjmax, Vr = 100% of max. datasheet reverse voltage | 1000 hours | 30 | 1280 | 0 | | |
| " 3 | | | 1000 110013 | 30 | 1200 | 0 | | |
| # 7 | TC Temperature Cycling | JESD22-A104 -65 °C to Tjmax, not to exceed 150°C | 1000 cycles | 23 | 1000 | 0 | | |
| # 8 or | UHAST Unbiased HAST | JESD22-A118 Tamb = 130 °C, RH = 85 % | | 23 | 1000 | 0 | | |
| # 8a | AC Autoclave | JESD22-A102 Tamb = 121 °C, RH = 100 % Pressure = 205 kPa (29.7 psia) | — 96 hours | | | | | |
| # 9 | H3TRB High Humidity High Temperature Reverse Bias | JESD22-A101 Tamb = 85 °C, RH = 85 %, VR = 80 % of rated reverse voltage ^[1] | 1000 hours | 23 | 1000 | 0 | | |
| # 10 | IOL Intermittent Operating Life | MIL-STD-750 Method 1037 ton = toff, devices powered to insure ΔTj = 100 °C for 15000 cycles | 1000 hours | n.a. | n.a. | n.a. | | |
| # 20 | RSH Resistance to Solder Heat | JESD22-A111 260 °C ± 5 °C | 10 s | n.a. | n.a. | 0 | | |
| # 21 | SD Solderability | J-STD-002 | | 21 | 630 | 0 | | |

^[1] The maximum applied voltage is limited by test chamber set up and does not exceed 115V.

Calculation of FIT and MTTF

Test considered for FIT calculation: High Temperature Reverse Bias (HTRB, Test #B1) Confidence level 60%, derated to 55 °C, activation energy 0.7 eV, test time 168 to 1000 hours

| Wafer Fab | Technology | Quantity | Rejects | Failure Rate (FIT) | MTTF (hrs) |
|-----------|-----------------|----------|---------|--------------------|------------|
| NXP ICN8 | Protection INDI | 1280 | 0 | 3,32 | 3,01E+08 |

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